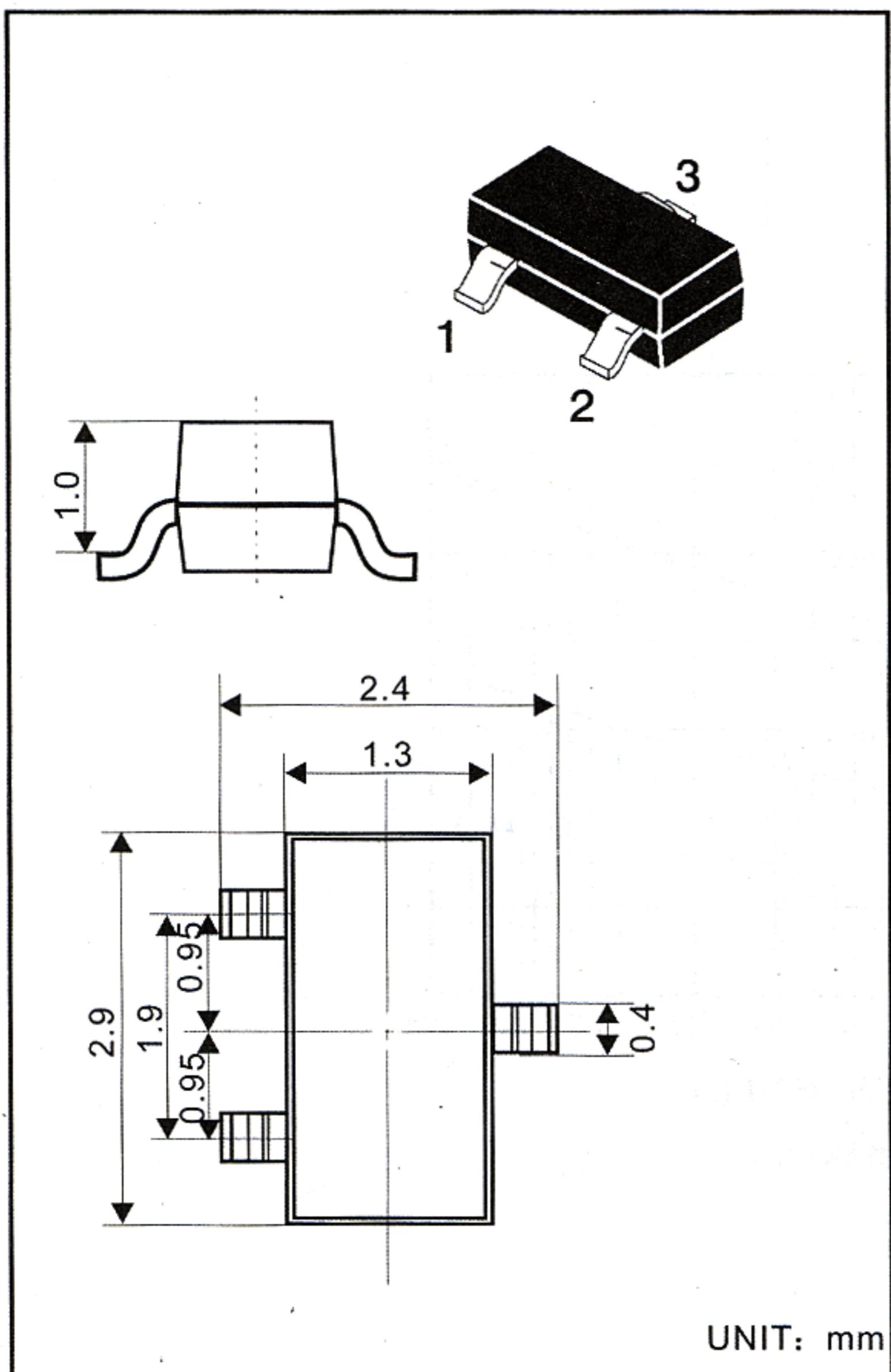


SOT-23 Plastic-Encapsulate DIODES

BAS21LT1 SWITCHING DIODE



FEATURES

Power dissipation

Pd: 225mW (Tamb=25°C)

Forward current

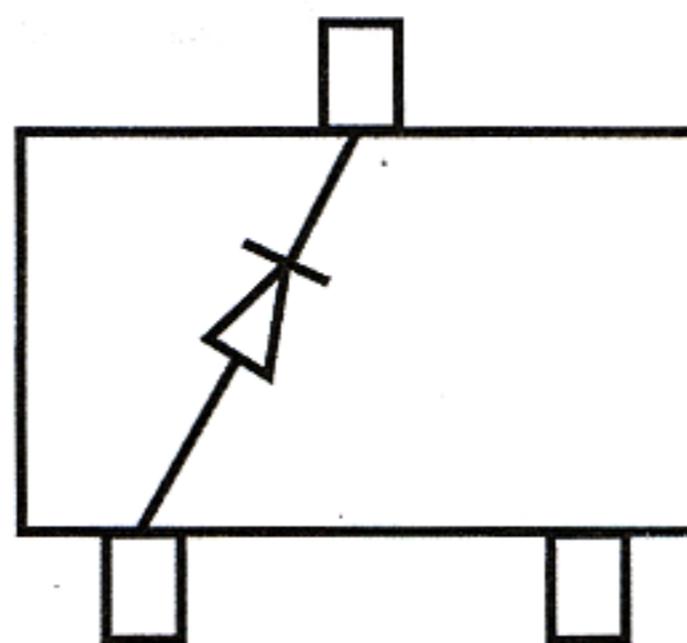
If: 200mA

Reverse voltage

Vr: 250V

Operating and storage junction temperature range

Tj,Tstg : -55°C to +150°C



MARKING: JS

ELECTRICAL CHARACTERISTICS

(Tamp=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Reverse breakdown voltage	V(BR)	If=100 µA	250		V
Reverse voltage leakage current	Ir	Vr=200V		1	µ A
Forward voltage	Vf	If=100mA If=200mA		1000 1250	mV
Diode capacitance	Ctot	Vr=0V, f=1MHz		5	pF
Reverse recovery time	trr	If=Ir=10mA Irr=0.1Ir		50	ns

Typical Characteristics

BAS21LT1

